# DATA SHEET



# BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC2756TB$

mm)

# MIXER+OSCILLATOR SILICON MMIC FOR FREQUENCY DOWNCONVERTER OF L BAND WIRELESS RECEIVER

#### DESCRIPTION

The  $\mu$ PC2756TB is a silicon monolithic integrated circuit designed as L band frequency downconverter for receiver stage of wireless systems. The IC consists of mixer and local oscillator. This IC operates at 3 V.

This IC is manufactured using NEC's 20GHz fr NESAT<sup>™</sup> III silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

#### FEATURES

| • | Wideband operation                   | :  | $f_{RFin} = 0.1$ to 2.0 GHz                                  |
|---|--------------------------------------|----|--|
| • | Supply voltage                       | :  | Vcc = 2.7 to 3.3 V   |
| • | Low current consumption              | :  | Icc = 6.0 mA TYP. @Vcc = 3.0 V                               |
| • | Minimized carrier leakage            | :  | Due to double balanced mixer                                 |
| • | Equable output impedance             | :  | Single-end push-pull IF amplifier                            |
| • | Equable temperature-drift oscillator | r: | Differential amplifier type oscillator                       |
| • | High-density surface mounting        | :  | 6-pin super minimold package (2.0 $\times$ 1.25 $\times$ 0.9 |
|   |                                      |    |  |

#### APPLICATIONS

- Data carrier up to 2.0 GHz MAX.
- Wireless LAN up to 2.0 GHz MAX.

#### ORDERING INFORMATION

| Part Number  | Package              | Marking | Supplying Form   |
|--------------|----------------------|---------|--|
| μPC2756TB-E3 | 6-pin super minimold | C1W     | <ul> <li>Embossed tape 8 mm wide</li> <li>1, 2, 3 pins face the perforation side of the tape</li> <li>Qty 3 kpcs/reel</li> </ul> |

**Remark** To order evaluation samples, please contact your local NEC sales office. Part number for sample order:  $\mu$ PC2756TB

#### Caution Electro-static sensitive devices

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

#### **PIN CONNECTIONS**



| Pin No. | Pin Name        |
|---------|-----------------|
| 1       | RFinput         |
| 2       | GND             |
| 3       | LO <sub>1</sub> |
| 4       | LO <sub>2</sub> |
| 5       | Vcc             |
| 6       | IFoutput        |

PRODUCT LINE-UP (TA =  $+25^{\circ}$ C, V cc = 3.0 V, Zs = ZL = 50  $\Omega$ )

| Parameter | Vcc        | lcc  | 0.9 GHz |      | 0.9 GHz | 1.6 GHz | <b>f</b> RFin | fiFout    | fosc   |                      |
|-----------|------------|------|---------|------|---------|---------|---------------|-----------|--------|----------------------|
| Part      |            |      | CG      | CG   | NF      | NF      |               |           |        | Package              |
| Number    | (V)        | (mA) | (dB)    | (dB) | (dB)    | (dB)    | (GHz)         | (GHz)     | (GHz)  |                      |
| μPC2756T  | 2.7 to 3.3 | 6.0  | 14      | 14   | 10      | 13      | 0.1 to 2.0    | 10 to 300 | to 2.2 | 6-pin minimold       |
| μPC2756TB |            |      |         |      |         |         |               |           |        | 6-pin super minimold |

Remark Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

#### INTERNAL BLOCK DIAGRAM



**Remark** Oscillator tank circuit must be externally attached to LO1 and LO2 pins.

# $\mu$ PC2756TB LOCATION EXAMPLE IN THE SYSTEM



This document is to be specified for  $\mu$ PC2756TB. For the other part number mentioned in this document, please refer to the data sheet of each part number.

#### PIN EXPLANATION

| Pin<br>No. | Pin Name        | Applied<br>Voltage<br>(V) | Pin<br>Voltage<br>(V) <sup>Note</sup> | Function and Application   | Equivalent Circuit |
|------------|-----------------|---------------------------|---------------------------------------|--|--------------------|
| 1          | RFinput         | _                         | 1.2                                   | This pin is RF input for mixer designed as double<br>balance type.<br>This circuit contributes to suppress spurious signal<br>with minimum LO and bias power consumption.<br>Also this symmetrical circuit can keep specified<br>performance insensitive to process-condition<br>distribution.<br>This pin must be externally coupled to front stage<br>with capacitor for DC cut. |                    |
| 2          | GND             | 0                         | -                                     | Must be connected to the system ground with<br>minimum inductance. Ground pattern on the board<br>should be formed as wide as possible.<br>(Track length should be kept as short as possible.)   |                    |
| 3          | LO1             | _                         | 1.2                                   | These pins are both base-collector of oscillator. This oscillator is designed as differential amplifier type.<br>3 pin and 4 pin should be externally equipped with tank resonator circuit in order to oscillate with feedback loop. Also this symmetrical circuit can keep  |                    |
| 4          | LO <sub>2</sub> | _                         | 1.2                                   | specified performance insensitive to process-<br>condition distribution.<br>Each pin must be externally coupled to tank circuit<br>with capacitor for DC cut.  |                    |
| 5          | Vcc             | 2.7 to 3.3                | -                                     | Supply voltage $3.0 \pm 0.3$ V for operation. Must be connected bypass capacitor (e.g. 1 000 pF) to minimize ground impedance.   |                    |
| 6          | IFoutput        | _                         | 1.7                                   | This pin is output from IF buffer amplifier designed as<br>single-ended push-pull type.<br>This pin is assigned for emitter follower output with<br>low-impedance. This pin must be externally coupled<br>to next stage with capacitor for DC cut.   | Vcc<br>(6)         |

Note Pin voltage is measured at Vcc = 3.0 V

#### APPLICATION

This IC is guaranteed on the test circuit constructed with 50  $\Omega$  equipment and transmission line. This IC, however, does not have 50  $\Omega$  input/output impedance, but electrical characteristics such as conversion gain and intermodulation distortion are described herein on these conditions without impedance matching. So, you should understand that conversion gain and intermodulation distortion at input level will vary when you improve VS of RF input with external circuit (50  $\Omega$  termination or impedance matching).

External circuits of the IC are explained in a following application note.

 To RF and IF port: Application Note "Usage and Application Characteristics of μPC2757T, μPC2758T and μPC8112T, 3-V Power Supply, 1.9-GHz Frequency Down Converter ICs for Cellular/Cordless Telephone and Portable Wireless Communication" (P11997E) \*

## ABSOLUTE MAXIMUM RATINGS

| Parameter                     | Symbol           | Conditions   | Rating      | Unit |
|-------------------------------|------------------|--|-------------|------|
| Supply Voltage                | Vcc              | T <sub>A</sub> = +25 °C  | 5.5         | V    |
| Power Dissipation             | PD               | Mounted on double-sided copper clad<br>$50 \times 50 \times 1.6$ mm epoxy glass PWB,<br>T <sub>A</sub> = +85°C | 270         | mW   |
| Operating Ambient Temperature | TA               |  | -40 to +85  | °C   |
| Storage Temperature           | T <sub>stg</sub> |  | -55 to +150 | °C   |

#### **RECOMMENDED OPERATING RANGE**

| Parameter      | Symbol | MIN. | TYP. | MAX. | Unit |
|----------------|--------|------|------|------|------|
| Supply Voltage | Vcc    | 2.7  | 3.0  | 3.3  | V    |

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = +25°C, V<sub>CC</sub> = 3.0 V, Z<sub>S</sub> = Z<sub>L</sub> = 50 Ω, Test circuit)

| Parameter                | Symbol    | Conditions   | MIN. | TYP. | MAX. | Unit |
|--------------------------|-----------|--|------|------|------|------|
| Circuit Current          | Icc       | No signals   | 3.5  | 6.0  | 8.0  | mA   |
| RF Input Frequency       | fRFin     | $\label{eq:GG} \begin{array}{l} CG \geq (CG1 - 3 \text{ dB}), \\ f_{\text{IFout}} = 150 \text{ MHz constant} \end{array}$                                      | 0.1  | -    | 2.0  | GHz  |
| IF Output Frequency      | fiFout    | $\label{eq:G} \begin{array}{l} CG \geq (CG1 - 3 \text{ dB}), \\ f_{\text{RFin}} = 0.9 \ \ GHz \ constant \end{array}$  | 10   | -    | 300  | MHz  |
| Conversion Gain 1        | CG1       | $\label{eq:result} \begin{array}{l} f_{\text{RFin}} = 0.9 \text{ GHz}, \ f_{\text{IFout}} = 150 \text{ MHz}, \\ P_{\text{RFin}} = -40 \text{ dBm} \end{array}$ | 11   | 14   | 17   | dB   |
| Conversion Gain 2        | CG2       | $f_{RFin} = 1.6 \text{ GHz}, f_{IFout} = 20 \text{ MHz},$<br>$P_{RFin} = -40 \text{ dBm}$  | 11   | 14   | 17   | dB   |
| SSB Noise Figure 1       | SSB•NF1   | f <sub>RFin</sub> = 0.9 GHz, f <sub>IFout</sub> = 150 MHz,<br>SSB mode   | _    | 10   | 13   | dB   |
| SSB Noise Figure 2       | SSB•NF2   | f <sub>RFin</sub> = 1.6 GHz, f <sub>IFout</sub> = 20 MHz,<br>SSB mode  | -    | 13   | 16   | dB   |
| Saturated Output Power 1 | Po(sat) 1 | $\label{eq:result} \begin{array}{l} f_{\text{RFin}} = 0.9 \text{ GHz}, \ f_{\text{IFout}} = 150 \text{ MHz}, \\ P_{\text{RFin}} = -10 \text{ dBm} \end{array}$ | -11  | -8   | -    | dBm  |
| Saturated Output Power 2 | PO(sat) 2 | $f_{RFin} = 1.6 \text{ GHz}, f_{IFout} = 20 \text{ MHz},$<br>$P_{RFin} = -10 \text{ dBm}$  | -15  | -12  | _    | dBm  |

# STANDARD CHARACTERISTICS FOR REFERENCE

(Unless otherwise specified, TA = +25°C, Vcc = 3.0 V, Zs = ZL = 50  $\Omega$ )

| Parameter                        | Symbol   | Conditions  | Reference | Unit   |
|----------------------------------|----------|---|-----------|--------|
| Output 3rd Order Intercept Point | OIP₃     | $f_{RFin} = 0.8$ to 2.0 GHz, $f_{IFout} = 0.1$ GHz, Cross point IP. | +4.0      | dBm    |
| Phase Noise                      | PN       | fosc = 1.9 GHz <sup>Note</sup>                                      | -68       | dBc/Hz |
| LO Leakage at RFinput Pin        | LOrf     | fLoin = 0.8 to 2.0 GHz  | -35       | dB     |
| LO Leakage at IFoutput Pin       | LOif     | f <sub>LOin</sub> = 0.8 to 2.0 GHz                                  | -23       | dB     |
| Maximum Oscillating Frequency    | foscmax. | V-Di: 1SV210, L: 7 nH <sup>Note</sup>                               | 2.2       | GHz    |

**Note** On application circuit example.

#### SCHEMATIC SUPPLEMENT FOR RF, IF SPECIFICATIONS



|          | MIN. | TYP. | MAX. | Unit |
|----------|------|------|------|------|
| CG1      | 11   | 14   | 17   | dB   |
| CG1-3 dB | 8    | 11   | 14   | dB   |

IF Frequency Response



#### **TEST CIRCUIT**



#### ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



#### COMPONENT LIST

|          | Value    |
|----------|----------|
| C1 to C3 | 1 000 pF |
| C4, C5   | 3 300 pF |

#### Notes

- (1)  $35 \times 42 \times 0.4$  mm double copper clad polyimide board.
- (2) Back side: GND pattern
- (3) Solder plated on pattern
- (4)  $\circ$  : Through holes
- (5) pattern should be removed on this testing.

### APPLICATION CIRCUIT EXAMPLE



# ILLUSTRATION OF THE APPLICATION CIRCUIT ASSEMBLED ON EVALUATION BOARD



#### COMPONENT LIST

|          | Value         |
|----------|---------------|
| C1 to C3 | 1 000 pF      |
| C4, C5   | 3 300 pF      |
| R1, R2   | 15 kΩ         |
| L        | 5 nH to 30 nH |
| V-Di     | HVU12         |

#### Notes

- (1)  $35 \times 42 \times 0.4$  mm double copper clad polyimide board.
- (2) Back side: GND pattern
- (3) Solder plated on pattern
- (4)  $\circ$  : Through holes
- (5) [\_\_\_\_] pattern should be removed on this testing.

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

#### ★ TYPICAL CHARACTERISTICS (Unless otherwise specified, T<sub>A</sub> = +25°C)

- ON THE TEST CIRCUIT -



- ON THE APPLICATION CIRCUIT -





#### - ON THE APPLICATION CIRCUIT -



Remark The graphs indicate nominal characteristics.

## S-PARAMETERS (Vcc = 3.0 V)

#### **RFinput Pin**



### **\*** PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)





#### NOTE ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as to minimize ground impedance (to prevent abnormal oscillation).
- (3) Keep the track length between the ground pins as short as possible.
- (4) Connect a bypass capacitor (example 1 000 pF) to the Vcc pin.
- (5) To construct oscillator, tank circuit must be externally attached to pin 3 and pin 4.

#### **RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

| Soldering Method | Soldering Conditions  | Recommended Condition Symbol |
|------------------|---|------------------------------|
| Infrared Reflow  | Package peak temperature: 235°C or below<br>Time: 30 seconds or less (at 210°C)<br>Count: 3, Exposure limit: None <sup>Note</sup> | IR35-00-3                    |
| VPS              | Package peak temperature: 215°C or below<br>Time: 40 seconds or less (at 200°C)<br>Count: 3, Exposure limit: None <sup>Note</sup> | VP15-00-3                    |
| Wave Soldering   | Soldering bath temperature: 260°C or below<br>Time: 10 seconds or less<br>Count: 1, Exposure limit: None <sup>Note</sup>          | WS60-00-1                    |
| Partial Heating  | Pin temperature: 300°C or below<br>Time: 3 seconds or less (per side of device)<br>Exposure limit: None <sup>Note</sup>           | -                            |

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

#### Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document **SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E)**.

[MEMO]



NESAT (NEC Silicon Advanced Technology) is a trademark of NEC Corporation.

- The information in this document is current as of February, 2001. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of customer's equipment shall be done under the full responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
  agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
  risks of damage to property or injury (including death) to persons arising from defects in NEC
  semiconductor products, customers must incorporate sufficient safety measures in their design, such as
  redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
   "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products
   developed based on a customer-designated "quality assurance program" for a specific application. The
   recommended applications of a semiconductor product depend on its quality grade, as indicated below.
   Customers must check the quality grade of each semiconductor product before using it in a particular
   application.
  - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
  - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
  - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).